

Nch 250V 4.0A Power MOSFET

| V_{DSS} | 250V |
|----------------------------|----------------|
| R _{DS(on)} (Max.) | 1300m Ω |
| I _D | 4.0A |
| P_D | 29W |

Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Drive circuits can be simple.
- 4) Parallel use is easy.
- 5) Pb-free lead plating; RoHS compliant
- 6) 100% Avalanche tested

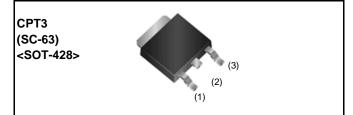
Application

Switching Power Supply

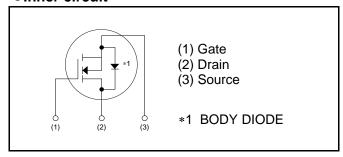
Automotive Motor Drive

Automotive Solenoid Drive

Outline



•Inner circuit



Packaging specifications

| | Packaging | Taping |
|------|---------------------------|--------|
| | Reel size (mm) | 330 |
| Type | Tape width (mm) | 16 |
| Туре | Basic ordering unit (pcs) | 2,500 |
| | Taping code | TL |
| | Marking | C41N25 |

• Absolute maximum ratings $(T_a = 25^{\circ}C)$

| Paramete | Symbol | Value | Unit | |
|--------------------------------|--------------------------|-------------------------|-------------|----|
| Drain - Source voltage | V_{DSS} | 250 | V | |
| Continuous drain surrent | $T_c = 25^{\circ}C$ | I _D *1 | ±4.0 | А |
| Continuous drain current | T _c = 100°C | I _D *1 | ±2.2 | А |
| Pulsed drain current | | I _{D,pulse} *2 | 16 | А |
| Gate - Source voltage | | V_{GSS} | ±30 | V |
| Avalanche energy, single pulse | | E _{AS} *3 | 1.61 | mJ |
| Avalanche current | | I _{AR} *3 | 2.0 | А |
| Power dissipation | T _c = 25°C | P _D | 29 | W |
| rower dissipation | $T_a = 25^{\circ}C^{*4}$ | P_{D} | 0.85 | W |
| Junction temperature | | T _j | 150 | °C |
| Range of storage temperature | | T _{stg} | -55 to +150 | °C |

●Thermal resistance

| Parameter | Symbol | Values | | | Unit |
|--|-------------------|--------|------|------|-------|
| - Farameter | Symbol | Min. | Тур. | Max. | Offic |
| Thermal resistance, junction - case | R_{thJC} | - | - | 4.3 | °C/W |
| Thermal resistance, junction - ambient *4 | R_{thJA} | - | - | 147 | °C/W |
| Soldering temperature, wavesoldering for 10s | T _{sold} | - | - | 265 | °C |

•Electrical characteristics($T_a = 25$ °C)

| Parameter | Symbol | Conditions | Values | | Unit | |
|---|------------------------|---------------------------------|--------|------|------|-------|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Offic |
| Drain - Source breakdown voltage | $V_{(BR)DSS}$ | $V_{GS} = 0V$, $I_D = 1mA$ | 250 | - | - | V |
| | | $V_{DS} = 250V, V_{GS} = 0V$ | | | 10 | |
| Zoro gato voltago drain current | l | $T_j = 25^{\circ}C$ | _ | - | 10 | ۸ |
| Zero gate voltage drain current | I _{DSS} | $V_{DS} = 250V, V_{GS} = 0V$ | | | 100 | μА |
| | | T _j = 125°C | | | 100 | |
| Gate - Source leakage current | I_{GSS} | $V_{GS} = \pm 30V, V_{DS} = 0V$ | - | ı | ±100 | nA |
| Gate threshold voltage | $V_{GS (th)}$ | $V_{DS} = 10V$, $I_D = 1mA$ | 3.5 | ı | 5.5 | V |
| | | $V_{GS} = 10V, I_D = 2.0A$ | - | 930 | 1300 | |
| Static drain - source on - state resistance | R _{DS(on)} *5 | $V_{GS} = 10V, I_D = 2.0A$ | | 1950 | 2730 | mΩ |
| | | T _j = 125°C | | 1950 | 2/30 | |
| Forward transfer admittance | g _{fs} | $V_{DS} = 10V, I_{D} = 2.0A$ | 1.1 | 2.2 | - | S |

●Electrical characteristics(T_a = 25°C)

| Parameter | Symbol | Conditions | | Unit | | |
|------------------------------|------------------------|------------------------------------|------|------|------|-------|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Offic |
| Input capacitance | C _{iss} | $V_{GS} = 0V$ | - | 350 | 1 | |
| Output capacitance | C _{oss} | V _{DS} = 25V | - | 30 | 1 | pF |
| Reverse transfer capacitance | C _{rss} | f = 1MHz | - | 15 | - | |
| Turn - on delay time | t _{d(on)} *5 | $V_{DD} \simeq 125V, V_{GS} = 10V$ | - | 15 | - | |
| Rise time | t _r *5 | $I_D = 2.0A$ | - | 14 | - | no |
| Turn - off delay time | t _{d(off)} *5 | $R_L = 12\Omega$ | - | 18 | - | ns |
| Fall time | t _f *5 | $R_G = 10\Omega$ | - | 15 | ı | |

•Gate Charge characteristics($T_a = 25$ °C)

| Parameter | Symbol | Conditions | Values | | | Unit |
|----------------------|------------------------|----------------------------------|--------|------|------|-------|
| - Farameter | Symbol | Conditions | Min. | Тур. | Max. | Offic |
| Total gate charge | Q_g^{*5} | V _{DD} ≃ 125V | - | 8.5 | 1 | |
| Gate - Source charge | ${\sf Q_{gs}}^{*5}$ | $I_D = 4.0A$ | - | 3.5 | - | nC |
| Gate - Drain charge | ${\sf Q_{gd}}^{*5}$ | V _{GS} = 10V | - | 3.5 | - | |
| Gate plateau voltage | V _(plateau) | $V_{DD} \simeq 125V, I_D = 4.0A$ | - | 7.8 | - | V |

●Body diode electrical characteristics (Source-Drain)(T_a = 25°C)

| Parameter | Symbol | Conditions | Values | | | - Unit |
|---------------------------|--------------------|-----------------------------|--------|------|------|--------|
| r ai ai ii etei | Symbol | Conditions | Min. | Тур. | Max. | Offic |
| Continuous source current | I _S *1 | T _c = 25°C | - | - | 4 | Α |
| Pulsed source current | I _{SM} *2 | 1 _c = 23 C | - | - | 16 | Α |
| Forward voltage | V _{SD} *5 | $V_{GS} = 0V, I_{S} = 4.0A$ | - | - | 1.5 | V |
| Reverse recovery time | t _{rr} *5 | I _S = 2.0A | - | 80 | - | ns |
| Reverse recovery charge | Q _{rr} *5 | di/dt = 100A/μs | - | 200 | - | nC |

^{*1} Limited only by maximum temperature allowed.

*5 Pulsed

^{*2} Pw \leq 10 μ s, Duty cycle \leq 1%

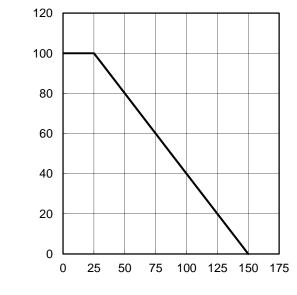
^{*3} L \simeq 500 μ H, V_{DD} = 50V, Rg = 10 Ω , starting T_j = 25°C

^{*4} Mounted on a epoxy PCB FR4 (20mm × 20mm × 0.8mm)

Power Dissipation: P_D/P_D max. [%]

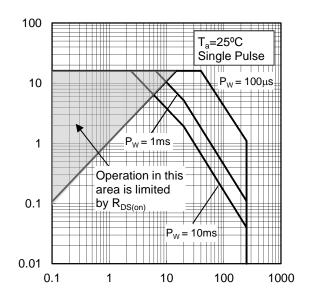
•Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve



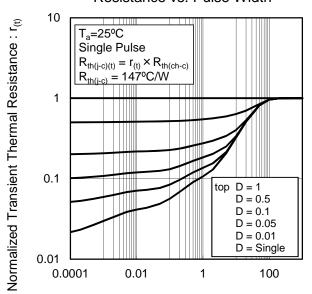
Junction Temperature : T_i [°C]

Fig.2 Maximum Safe Operating Area



Drain - Source Voltage : V_{DS} [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



Pulse Width : $P_W[s]$

Drain Current: I_D [A]

• Electrical characteristic curves

Fig.4 Avalanche Current vs Inductive Load

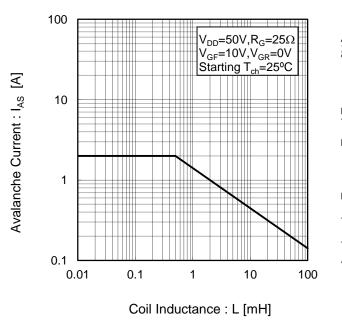
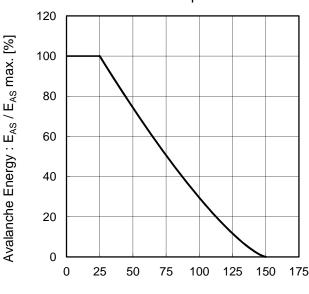
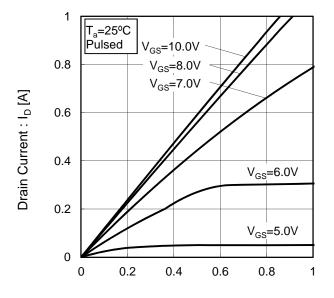


Fig.5 Avalanche Energy Derating Curve vs Junction Temperature



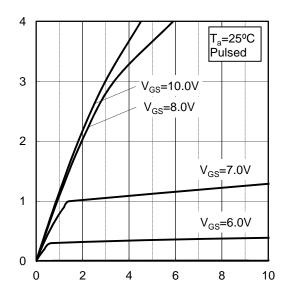
Junction Temperature : T_i [°C]

Fig.6 Typical Output Characteristics(I)



Drain - Source Voltage : V_{DS} [V]

Fig.7 Typical Output Characteristics(II)



Drain - Source Voltage : V_{DS} [V]

Drain Current : I_D [A]

• Electrical characteristic curves

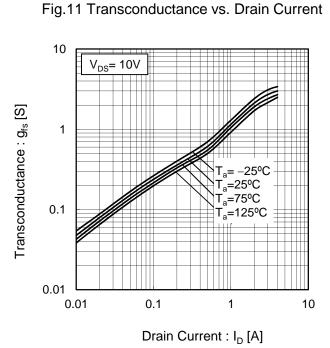
Fig.8 Breakdown Voltage vs. Junction Temperature 340 Normarize Drain - Source Breakdown Voltage $V_{GS} = 0V$ $I_D = 1mA$ 320 300 $: V_{(BR)DSS}[V]$ 280 260 240 220 -50 0 50 100 150 Junction Temperature : T_j [°C]

10 $V_{DS} = 10V$ 1 Drain Current: I_D [A] 0.1 _a= 125°C T̃_a= 75°C $T_a = 25^{\circ}C$ -25°C 0.01 0.001 0 2 6 8 10

Gate - Source Voltage : V_{GS} [V]

Fig.9 Typical Transfer Characteristics

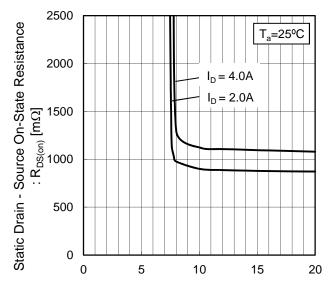
Fig.10 Gate Threshold Voltage vs. Junction Temperature 5.5 $V_{DS} = 10V$ Gate Threshold Voltage: V_{GS(th)} [V] $I_D = 1 \text{mA}$ 5.0 4.5 4.0 3.5 3.0 2.5 -50 -25 0 25 50 75 100 125 150 Junction Temperature : T_i [°C]





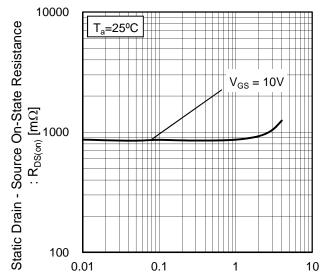
• Electrical characteristic curves

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



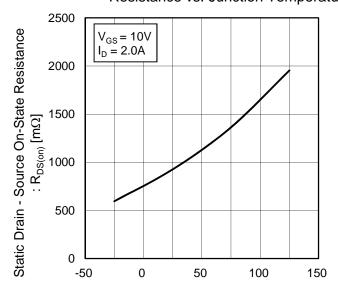
Gate - Source Voltage : V_{GS} [V]

Fig.13 Static Drain - Source On - State Resistance vs. Drain Current(I)



Drain Current : I_D [A]

Fig.14 Static Drain - Source On - State
Resistance vs. Junction Temperature

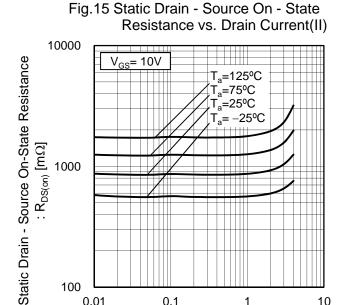


Junction Temperature : T_j [°C]

100

0.01

•Electrical characteristic curves



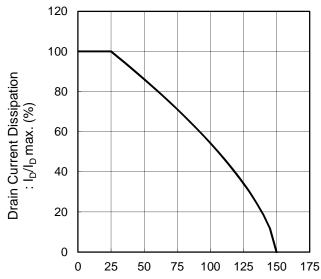
0.1

Drain Current : I_D [A]

1

10

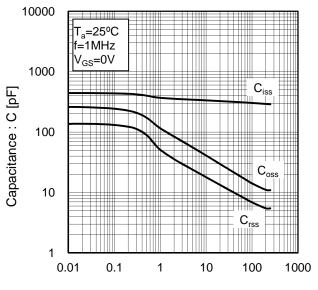
Fig.16 Drain Current Derating Curve



Junction Temperature : T_i [°C]

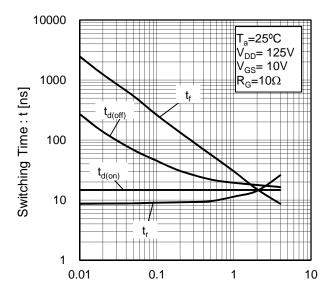
•Electrical characteristic curves

Fig.17 Typical Capacitance vs. Drain - Source Voltage



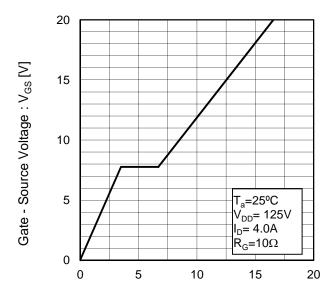
Drain - Source Voltage : V_{DS} [V]

Fig.18 Switching Characteristics



Drain Current : I_D [A]

Fig.19 Dynamic Input Characteristics



Total Gate Charge : Q_g [nC]

•Electrical characteristic curves

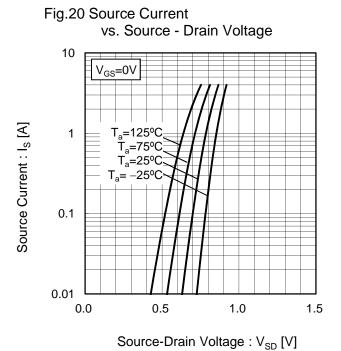


Fig21 Reverse Recovery Time
vs. Source Current

1000

Ta=25°C
di / dt = 100A / µs
V_{GS} = 0V

10

Source Current : I_S [A]

●Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

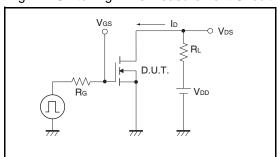


Fig.2-1 Gate Charge Measurement Circuit

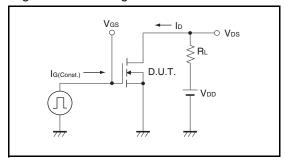


Fig.3-1 Avalanche Measurement Circuit

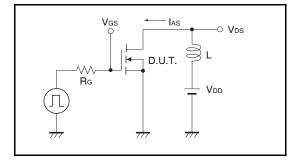


Fig.1-2 Switching Waveforms

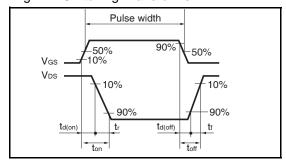


Fig.2-2 Gate Charge Waveform

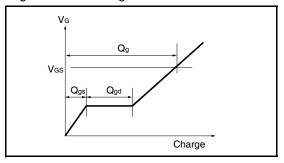
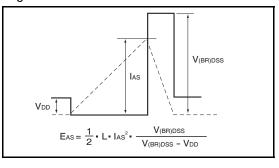
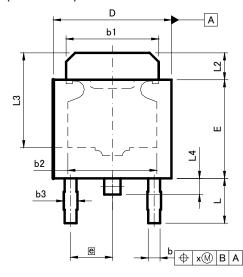


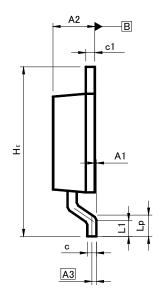
Fig.3-2 Avalanche Waveform

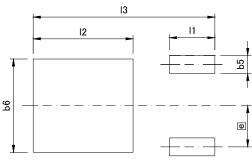


●Dimensions (Unit : mm)

CPT3







| DIM | MILIMI | MILIMETERS INCHES | | HES |
|-----|--------|-------------------|-------|-------|
| DIM | MIN | MAX | MIN | MAX |
| A1 | 0.00 | 0.15 | 0 | 0.006 |
| A2 | 2.20 | 2.50 | 0.087 | 0.098 |
| A3 | 0.2 | 25 | 0.0 | 01 |
| b | 0.55 | 0.75 | 0.022 | 0.03 |
| b1 | 5.00 | 5.30 | 0.197 | 0.209 |
| b2 | 5.0 | 00 | 0.2 | 20 |
| b3 | 0. | 75 | 0.0 | 03 |
| С | 0.40 | 0.60 | 0.016 | 0.024 |
| c1 | 0.40 | 0.60 | 0.016 | 0.024 |
| D | 6.30 | 6.70 | 0.248 | 0.264 |
| E | 5.40 | 5.80 | 0.213 | 0.228 |
| е | 2.3 | 30 | 0.0 | 09 |
| HE | 9.00 | 10.00 | 0.354 | 0.394 |
| L | 2.20 | 2.80 | 0.087 | 0.11 |
| L1 | 0.80 | 1.40 | 0.031 | 0.055 |
| L2 | 1.20 | 1.80 | 0.047 | 0.071 |
| L3 | 5.3 | 5.30 | | 09 |
| L4 | 0.9 | 90 | 0.0 | 35 |
| Lp | 1.00 | 1.60 | 0.039 | 0.063 |
| Х | _ | 0.25 | _ | 0.01 |

| DIM | MILIMETERS | | INC | INCHES | |
|-----|------------|-------|-----|--------|--|
| DIM | MIN | MAX | MIN | MAX | |
| b5 | - | 1.00 | - | 0.04 | |
| b6 | - | 5.20 | - | 0.205 | |
| l1 | - | 2.50 | - | 0.098 | |
| 12 | - | 5.50 | - | 0.217 | |
| 13 | _ | 10.00 | _ | 0.394 | |

Dimension in mm/inches

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| JÁPAN | USA | EU | CHINA |
|---------|--------|------------|-----------|
| CLASSⅢ | СГУССШ | CLASS II b | CL ACCIII |
| CLASSIV | CLASSⅢ | CLASSⅢ | CLASSⅢ |

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 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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